

Features

- Low operating voltage: 1.5V
- Ultra low capacitance: 0.2pF (Typ)
- Ultra low leakage: nA level
- Low clamping voltage
- -IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 15\text{kV}$
 - Contact discharge: $\pm 12\text{kV}$
- -IEC61000-4-4 (EFT) 40A (5/50ns)
- -IEC61000-4-5 (Lightning) 4A (8/20 μs)
- 2-pin leadless package
- These are Pb-Free Devices
- Response Time is Typically < 1 ns

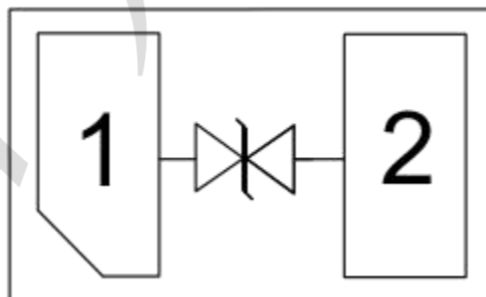
Mechanical Characteristics

- Package: DFN1006-2(0402)
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound
- Terminal Connections: See Diagram Below
- -IEC 61000-4-2 (ESD) immunity test

Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- USB Type-C Interface
- USB 3.1 / 3.2 Interface

Dimensions and Pin Configuration



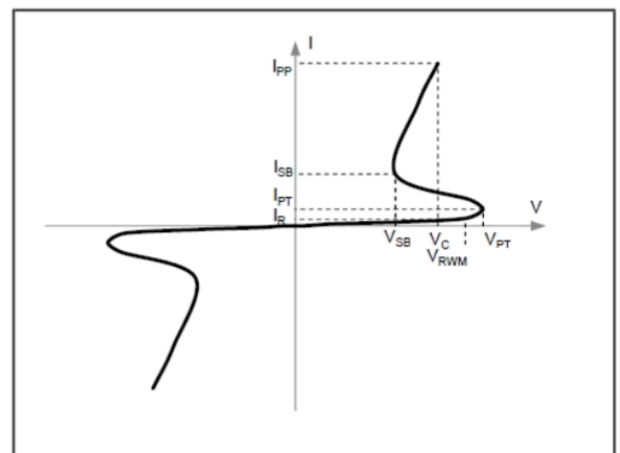
Absolute Maximum Ratings (T_{amb}=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	14	W
Peak Pulse Current (8/20μs)	I _{pp}	4	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±15 ±12	KV
Operating Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}	--	--	1.5	V	
Breakdown Voltage	V _{BR}	4.5	6.0	--	V	I _T = 1mA
Reverse Leakage Current	I _R	--	--	0.1	uA	V _{RWM} =1.5V
Clamping Voltage	V _C	--	1.9	--	V	I _{pp} =1A(8x 20us pulse)
Clamping Voltage	V _C	--	2.9	3.5	V	I _{pp} =4A(8x 20us pulse)
Junction Capacitance	C _J	--	0.2	0.3	pF	V _R = 0V, f = 1MHz

Symbol	Definition
I _{PP}	Peak Pulse Current
V _C	Clamping Voltage
V _{RWM}	Reverse Working Voltage
I _R	Reverse Leakage Current
V _{BR}	Breakdown Voltage
I _T	Test Current
V _{PT}	Punch-Through Voltage
I _{PT}	Punch-Through Current



Characteristic Curves

Fig1. 8/20 μ s Pulse Waveform

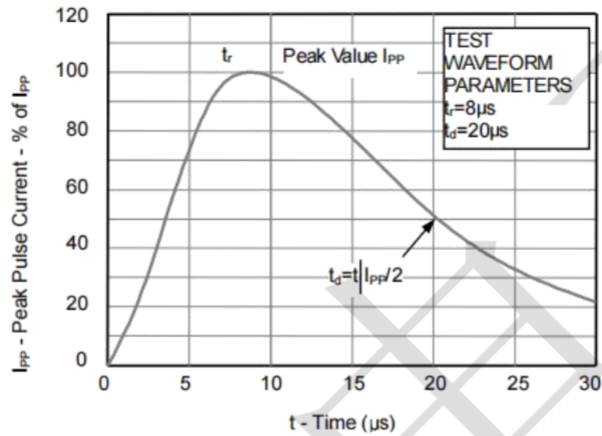


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

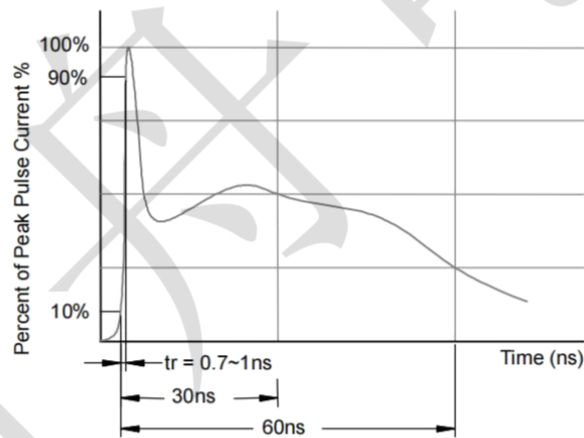
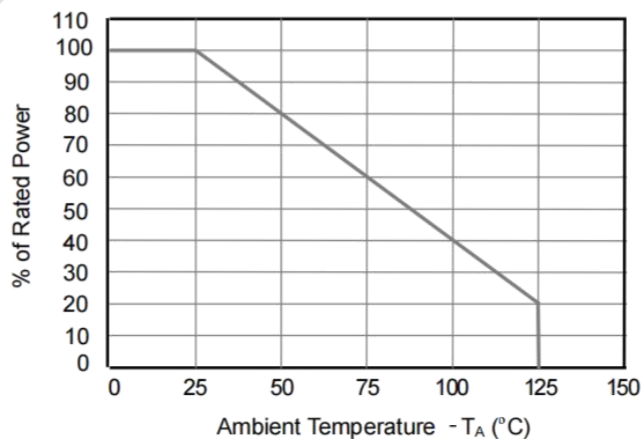
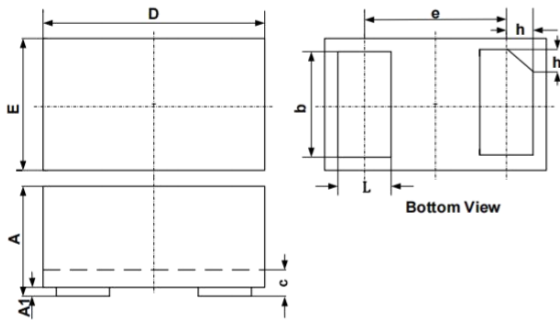


Fig3. Power Derating Curve



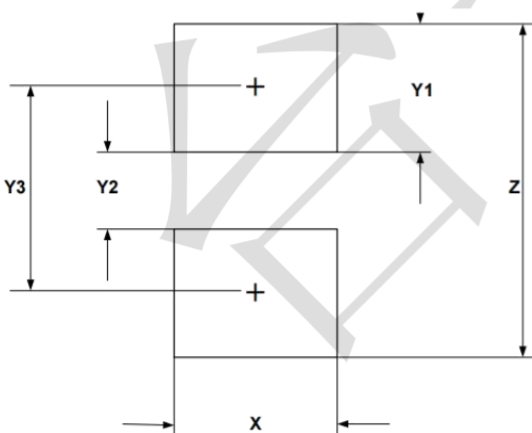
Package Outline & Dimensions

DFN1006-2 (0402)



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052